



PRODUCT DATA SHEET



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Please note: Please check the JINGAO Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.jg-semi.cn. Please email any questions regarding the system integration to JINGAO_questions@jgsemi.com.



USBLC6-2P6

SuperESD

Description

The USBLC6-2P6 is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability. Low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium.

Features

- IEC 61000-4-2 Level 4 ESD Protection
 - ±12kV Contact Discharge
 - ±17kV Air Discharge
- IEC 61000-4-4 EFT Protection
 - 40A (5/50ns)
- IEC 61000-4-5 Surge
 - 4.5A (8/20us)

- RoHS compliance
- Protecting two I/O line
- Ultra-low Capacitance:0.6pF (Typical)
- Low clamping voltage
- Low leakage current
- Solid-state silicon technology

Applications

- HDMI/USB2.0
- Monitors and flat panel display
- 10/100/1000 ethernet

- Notebook computers
- SIM ports
- ATM interface

Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size	
USBLC6-2P6	SOT-563	F	Halogen free	Tape & Reel	3K PCS	UL 94V-0	7 inches	

Table-1Ordering information



Pin Configuration and Functions

Pin	Name	Description	Outline	Circuit Diagram				
1	Ю	Connect to IO						
2	GND	Connect to GND		5				
3	Ю	Connect to IO	F					
4	Ю	Connect to IO	•					
5	Vcc	Connect to Vcc		2				
6	Ю	Connect to IO						

Table-2 Pin configuration

Absolute Maximum rating

Over operating free-air temperature range (unless otherwise noted)

Parameters	Symbol	Min.	Max.	Unit
Peak pulse power (tp=8/20us)@25°C	P_{pk}	-	60	W
Peak pulse current (tp=8/20us)@25°C	I _{PP}	-	4.5	А
ESD (IEC61000-4-2 air discharge) @25°C	V_{ESD}	-	±17	kV
ESD (IEC61000-4-2 contact discharge) @25°C	V_{ESD}	-	±12	kV
Junction temperature	TJ	-	150	°C
Operating temperature	T _{OP}	-40	125	°C
Storage temperature	T _{STG}	-55	150	°C
Lead temperature	T_L	-	260	°C

Table-3 Absolute Maximum rating



Electrical Characteristics

At TA = 25° C unless otherwise noted

Parameters	Symbol	conditions	Min.	Тур.	Max.	Unit
Reverse stand-off voltage	V _{RWM}				5	V
Reverse Breakdown Voltage	V_{BR}	I⊤= 1mA	6			V
Reverse Leakage Current	I _R	V _{RWM} =5V			1	uA
Peak Pulse Current	Ірр	TP=8/20us@25°C		4.5		А
Clamping Voltage	V _{CL}	I _{PP} =1A; TP=8/20us		8.5		
Clamping Voltage	V _{CL}	I _{PP} =4.5A; TP=8/20us		12		V
		I/O pins to ground;				
lunction conscitance	CJ	V _R =0V; f = 1MHz		0.6		~F
Junction capacitance		Between I/O pins;				рг
		V _R =0V; f = 1MHz		0.3		

Table-4 Electrical Characteristics



Typical Characteristic



Typical Application



Typical Interface Application



USBLC6-2P6

Dimensions and Land Pattern (SOT-563)









Units in millimeters

symbol	A	В	С	D	E	F	G	Н	I	J
Min.	1.50	0.50	1.55	1.10	0.15	0.50	0.00	0.10	0.10	0.15
Max.	1.70	0.60	1.70	1.25	0.30	0.60	0.05	0.18	0.30	0.20





Note:

- 1. Controlling dimension: in millimeters
- 2. General tolerance: ± 0.05 mm
- 3. The pad layout is for reference only





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